



$V_{DS} = 1200 \text{ V}$
 $I_D @ 25^\circ\text{C} = 105\text{A}$
 $R_{DS(ON)} = 18\text{m}\Omega$

Features

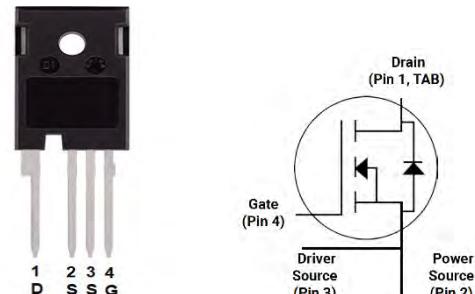
- High Blocking Voltage
- High Frequency Operation
- Low on-resistance
- Fast intrinsic diode with low reverse recovery
- 100% avalanche tested

Benefits

- Higher System Efficiency
- Parallel Device Convenience without thermal runaway
- High Temperature Application
- Hard Switching & Higher Reliability
- Easy to drive

Applications

- Motor Drives
- Solar / Wind Inverters
- EV Charging Station
- AC/DC converters
- DC/DC converters
- Uninterruptable power supplies



TO-247-4L Pin definition

Maximum Ratings ($T_c=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Value	Unit
Drain - Source Voltage	$V_{DS\max}$	$V_{GS}=0\text{V}, I_D=100\mu\text{A}$	1200	V
Gate - Source Voltage (dynamic)	$V_{GS\max}$	AC ($f>1 \text{ Hz}$)	-10 / +25	V
Gate - Source Voltage (static)	V_{GSop}	static	-5 / +20	V
Continuous Drain Current	I_D	$V_{GS} = 20\text{V}, T_c=25^\circ\text{C}$ $V_{GS} = 20\text{V}, T_c=100^\circ\text{C}$	105 74	A
Pulsed Drain Current	$I_{D(\text{pulse})}$	$T_c=25^\circ\text{C}$	220	A
Total power dissipation	P_D	$T_c=25^\circ\text{C}$	428	W
Avalanche Capability	E_{AS}	$V_{DD} = 100\text{V}, V_{GS}=20\text{V}, L=2\text{mH}$	784	mJ
Avalanche Capability	I_{AV}	$V_{DD} = 100\text{V}, V_{GS}=20\text{V}, L=2\text{mH}$	28	A
Operating Junction Temperature	T_J		-55 to 175	°C
Storage Temperature	T_{STG}		-55 to 175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



Reverse Diode Characteristics ($T_C=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Diode Forward Voltage	V_{SD}	$V_{GS} = -5V, I_{SD} = 25A,$		4.3		V
		$V_{GS} = -5V, I_{SD} = 25A,$ $T_J = 150^\circ C$		3.9		
		$V_{GS} = -5V, I_{SD} = 25A,$ $T_J = 175^\circ C$		3.8		
Continuous Diode Forward Current	I_S	$V_{GS} = -5V$			91	A
Reverse Recovery time	t_{rr}	$V_{GS} = -5V, I_{SD} = 50A,$ $V_R = 800V, dI/dt = 3700 A/\mu s$		30		ns
Reverse Recovery Charge	Q_{rr}			970		
Peak Reverse Recovery Current	I_{rrm}			53		

Thermal Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Thermal Resistance (per device)	$R_{th(j-c)}$	junction-case		0.27	0.35	${}^{\circ}C/W$



Typical Performance

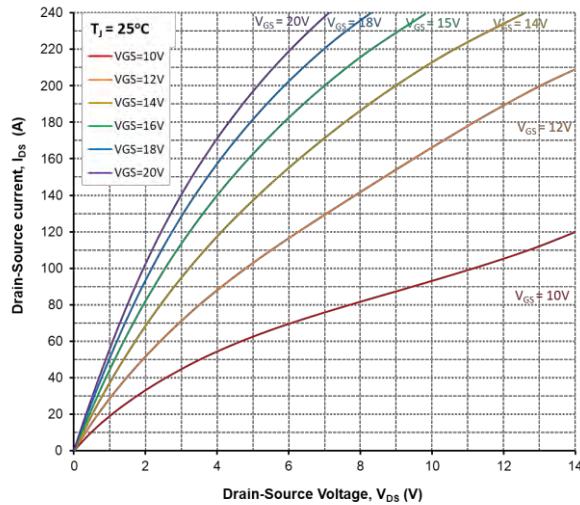


Figure 1. Output Characteristics, $T_J = 25^\circ\text{C}$

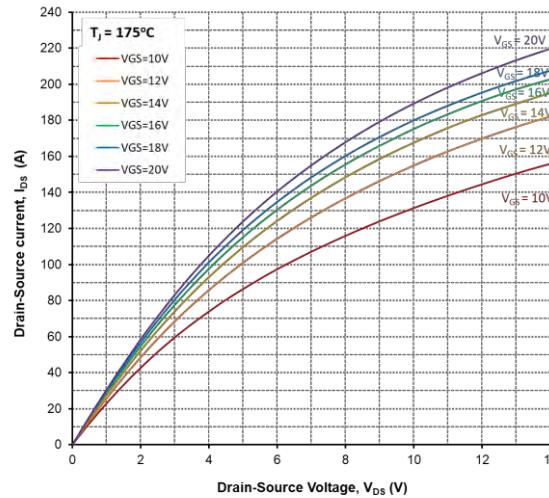


Figure 2. Output Characteristics, $T_J = 175^\circ\text{C}$

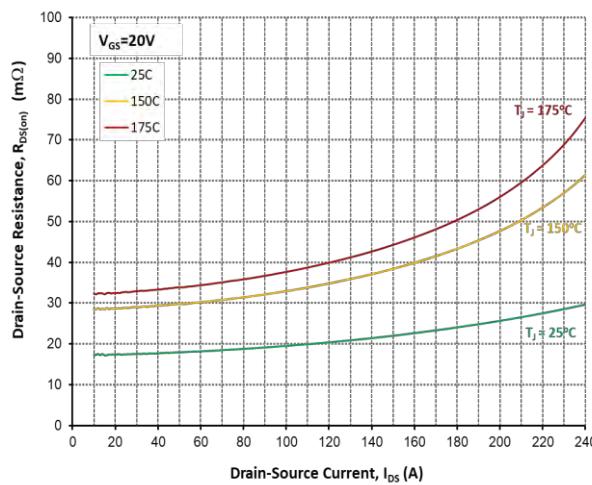


Figure 3. On-Resistance vs. Drain Current For Various Temperatures

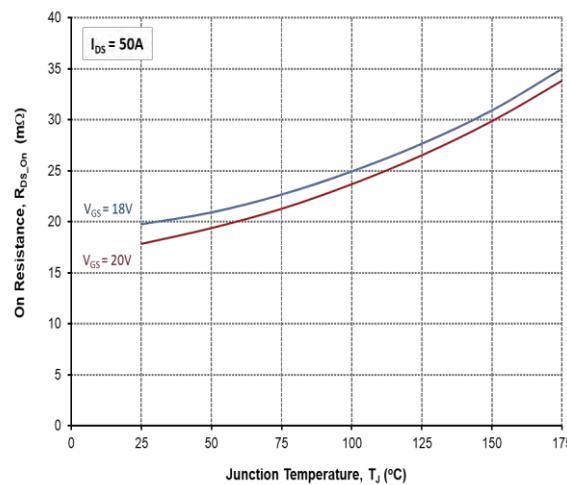


Figure 4. On-Resistance vs. Temperature

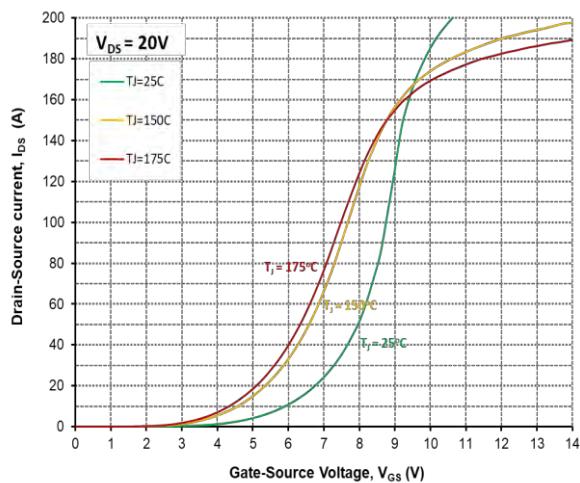


Figure 5. Transfer Characteristic For Various Junction Temperatures

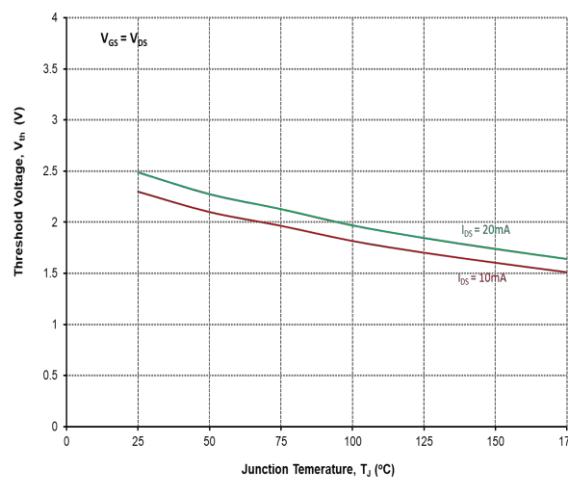


Figure 6. Threshold Voltage vs. Temperature



Typical Performance

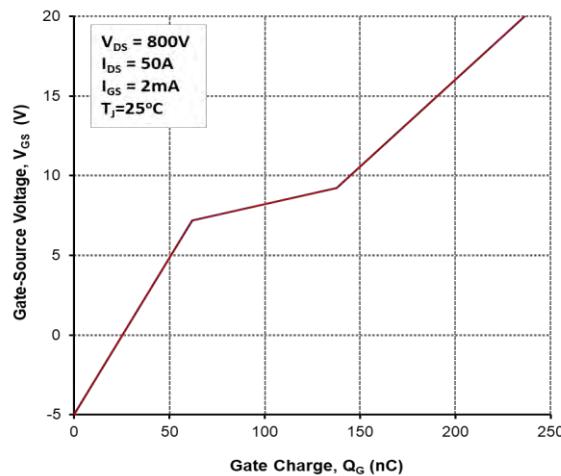


Figure 7. Gate Charge Characteristics

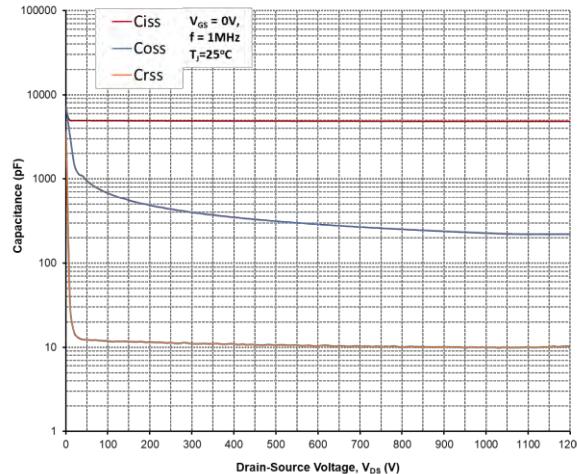


Figure 8. Capacitances vs. Drain-Source Voltage (0-1200V)

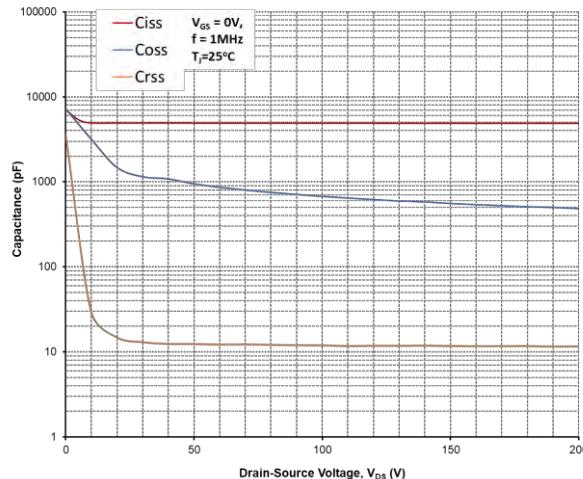


Figure 9. Capacitances vs. Drain-Source Voltage (0-200V)

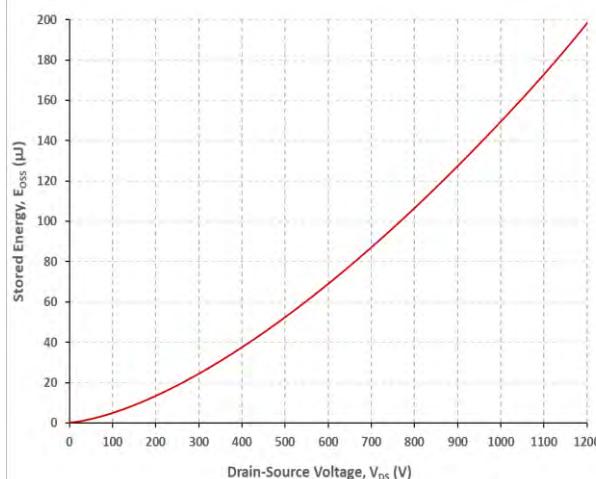


Figure 10. Output Capacitor Stored Energy

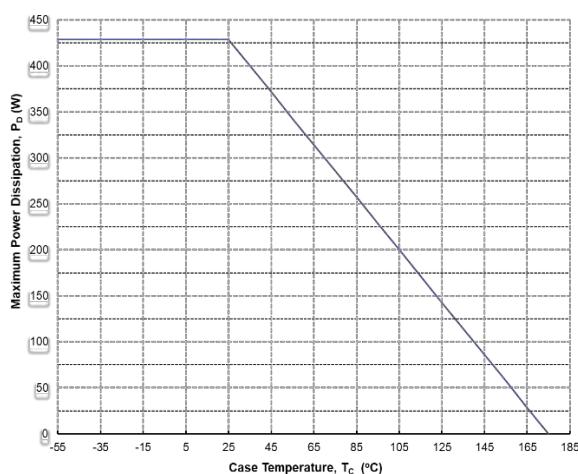


Figure 11. Maximum Power Dissipation Derating vs. Case Temperature

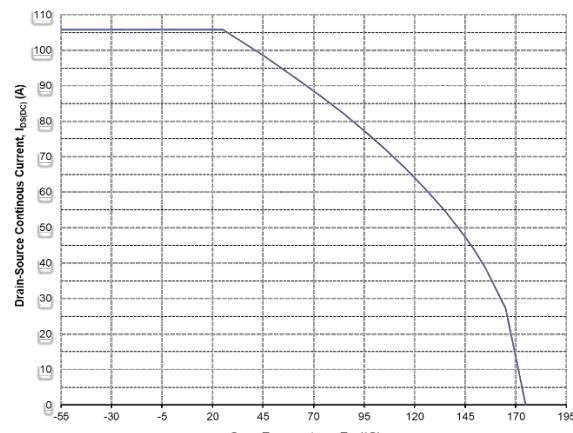


Figure 12. Continuous Drain Current Derating vs. Case Temperature



Typical Performance

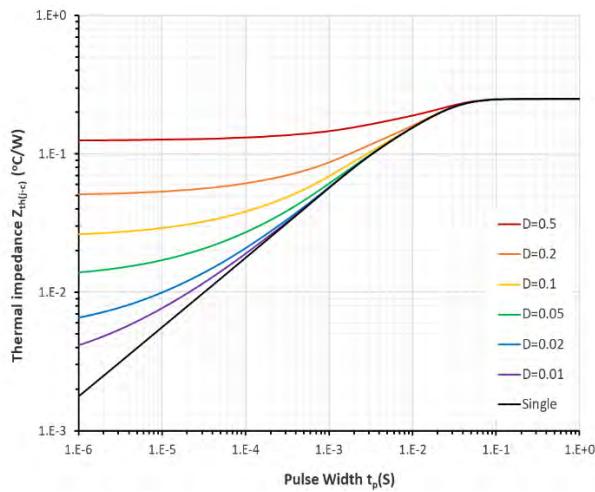
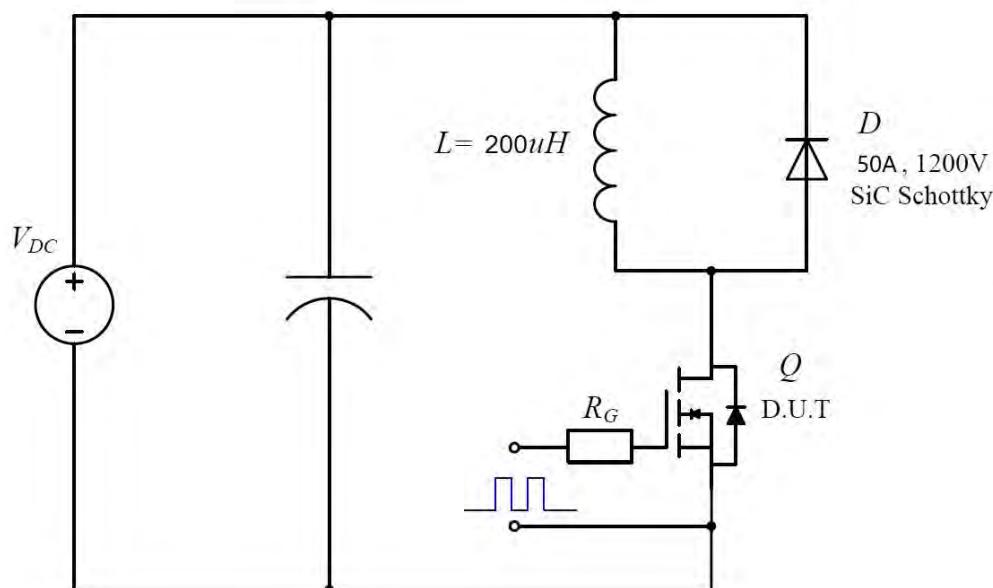
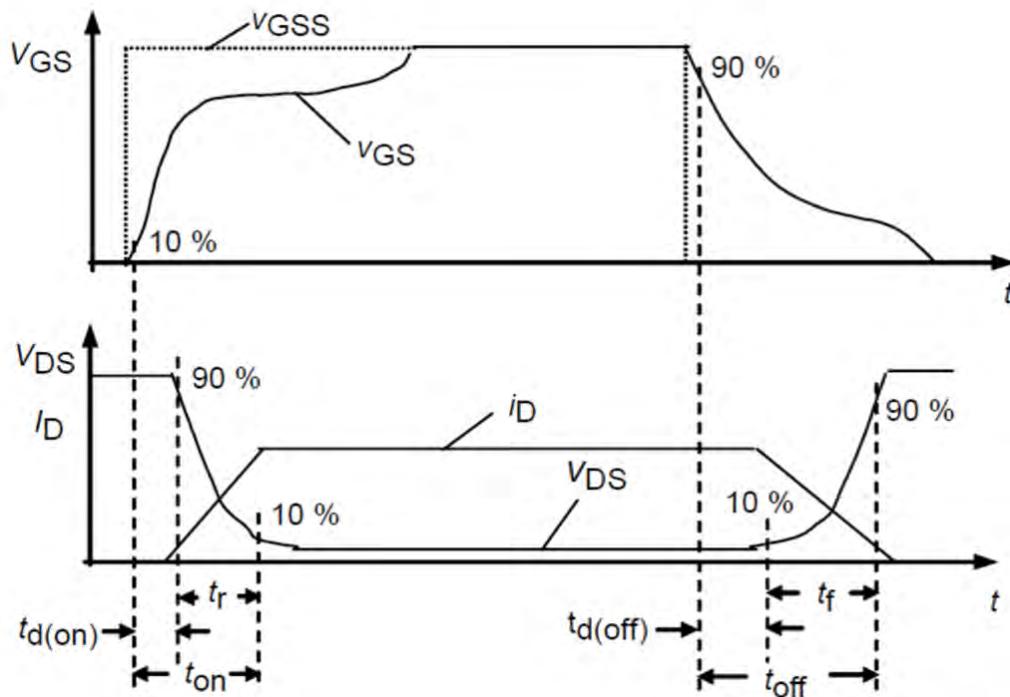


Figure 19. Transient Thermal Impedance
(Junction – Case)



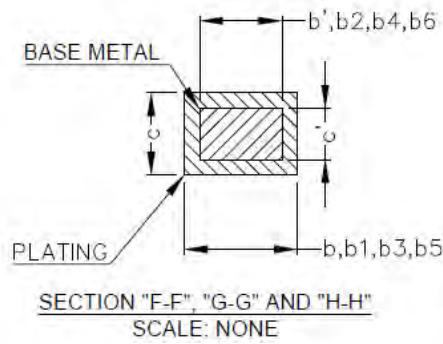
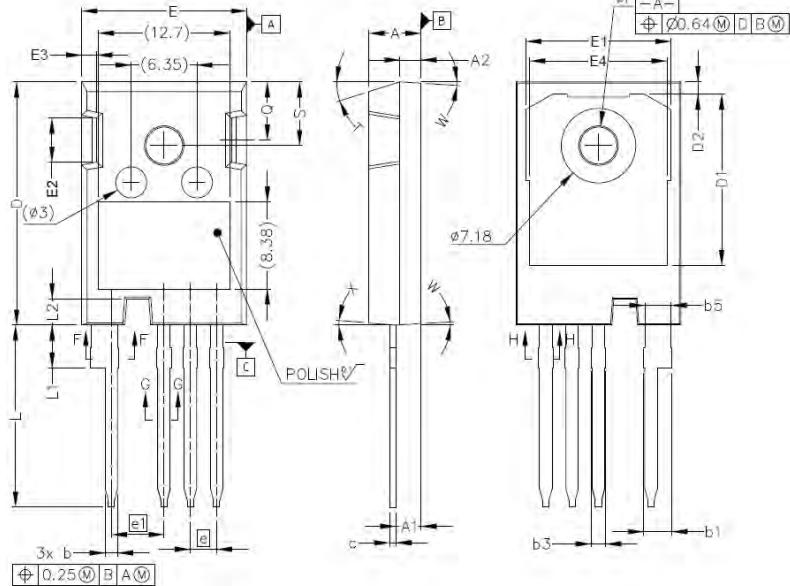
Switching Times Definition and Test Circuit





Package Dimensions

(TO-247-4L Package)



SYMBOL	MILLIMETERS	
	MIN	MAX
A	4.83	5.21
A1	2.29	2.54
A2	1.91	2.16
b'	1.07	1.28
b	1.07	1.33
b1	2.39	2.94
b2	2.39	2.84
b3	1.07	1.60
b4	1.07	1.50
b5	2.39	2.69
b6	2.39	2.64
c'	0.55	0.65
c	0.55	0.68
D	23.30	23.60
D1	16.25	17.65
D2	0.95	1.25
E	15.75	16.13
E1	13.10	14.15
E2	3.68	5.10
E3	1.00	1.90
E4	12.38	13.43
e	2.54 BSC	
e1	5.08 BSC	
N	4	
L	17.31	17.82
L1	3.97	4.37
L2	2.35	2.65
øP	3.51	3.65
Q	5.49	6.00
S	6.04	6.30
T	17.5° REF.	
W	3.5 ° REF.	
X	4 ° REF.	

NOTE :

1. ALL METAL SURFACES: TIN PLATED, EXCEPT AREA OF CUT
2. DIMENSIONING & TOLERANCING CONFIRM TO ASME Y14.5M-1994.
3. ALL DIMENSIONS ARE IN MILLIMETERS.
ANGLES ARE IN DEGREES.